Silicon Controlled Rectifiers Reverse Blocking Thyristors

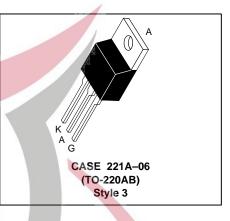
Designed primarily for half-wave ac control applications, such as motor controls, heating controls, and power supplies; or wherever half-wave, silicon gate-controlled devices are needed.

- Blocking Voltage to 800 Volts
- On-State Current Rating of 16 Amperes RMS
- High Surge Current Capability 160 Amperes
- Industry Standard TO–220AB Package for Ease of Design
- Glass Passivated Junctions for Reliability and Uniformity



*Motorola preferred devices

SCRs 16 AMPERES RMS 400 thru 800 VOLTS



MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Parameter	Symbol	Value	Unit	
MCI	R16D R16M R16N	400 600 800	Volts	
On-State RMS Current (All Conduction Angles)	IT(RMS)	16	A	
Peak Non-repetitive Surge Current (One Half Cycle, 60 Hz, T _J = 125°C)	ITSM	160	A	
Circuit Fusing Consideration (t = 8.3 ms)	l ² t	106	A ² sec	
Peak Gate Power (Pulse Width \leq 1.0 µs, T _C = 80°C)	P _{GM}	5.0	Watts	
Average Gate Power (t = 8.3 ms, T _C = 80°C)	PG(AV)	0.5	Watts	
Peak Gate Current (Pulse Width ≤ 1.0 μs, T _C = 80°C)	IGM	2.0	A	
Operating Junction Temperature Range	ELECTR	-40 to +125	°C	
Storage Temperature Range	T _{stg}	-40 to +150	°C	
THERMAL CHARACTERISTICS	·		•	
	i			

Thermal Resistance — Junction to Case — Junction to Ambient	R _{θJC} R _{θJA}	1.5 62.5	°C/W
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	ΤL	260	°C

(1) VDRM and VRRM for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

Preferred devices are Motorola recommended choices for future use and best overall value. REV 1

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MCR16 SERIES

ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Peak Forward Blocking Current $T_J = 25^{\circ}C$ Peak Reverse Blocking Current $T_J = 125^{\circ}C$ $(V_{AK} = Rated V_{DRM} \text{ or } V_{RRM}, Gate Open)$ $T_J = 125^{\circ}C$	I _{DRM} I _{RRM}	_		0.01 2.0	mA
ON CHARACTERISTICS					
Peak On-State Voltage* (I _{TM} = 32 A)	VTM	—	—	1.7	Volts
Gate Trigger Current (Continuous dc) (V _D = 12 V, R _L = 100 Ω)	IGT	2.0	8.0	20	mA
Gate Trigger Voltage (Continuous dc) (V _D = 12 V, R _L = 100 Ω)	VGT	0.5	0.65	1.0	Volts
Hold Current (Anode Voltage =12 V)	IН	4.0	25	40	mA
DYNAMIC CHARACTERISTICS					
Critical Rate of Rise of Off–State Voltage ($V_D = Rated V_{DRM}$, Exponential Waveform, Gate Open, $T_J = 25^{\circ}C$)	dv/dt	50	200	_	V/µs

*Indicates Pulse Test: Pulse Width \leq 2.0 ms, Duty Cycle \leq 2%.

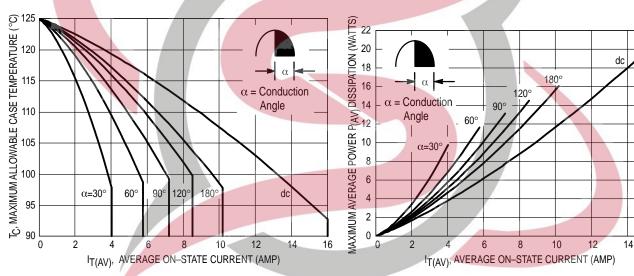
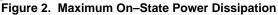


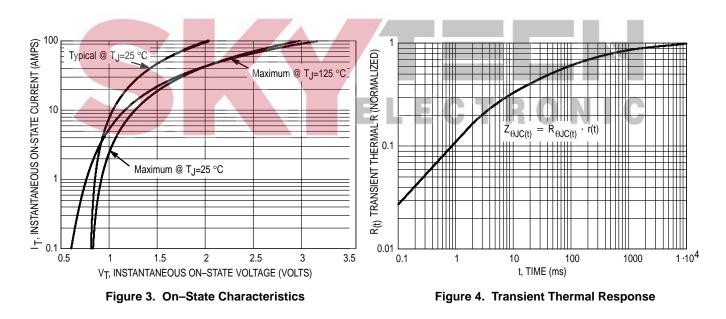
Figure 1. Average Current Derating

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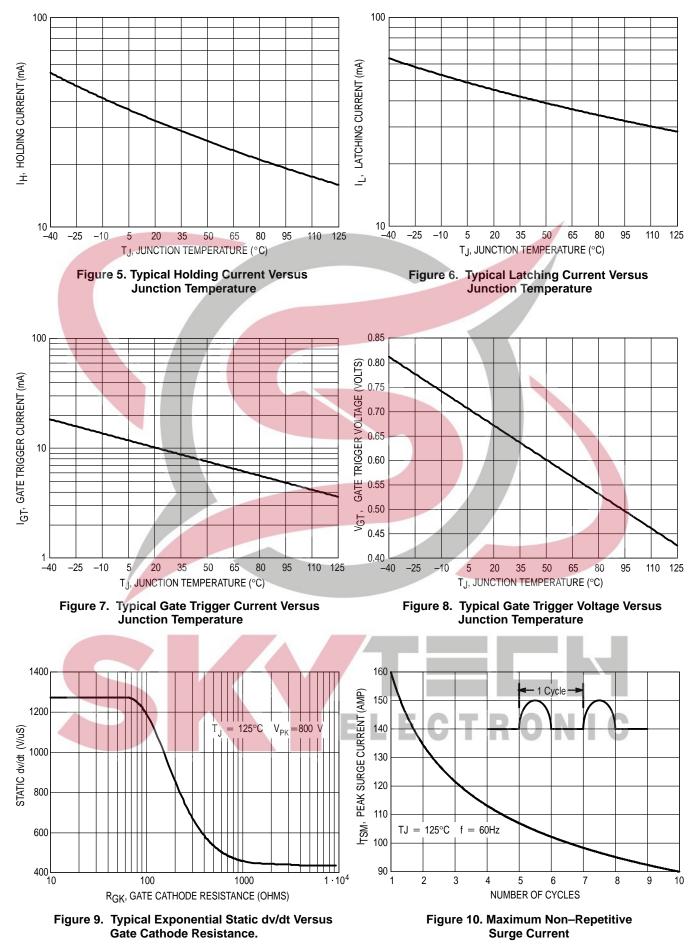
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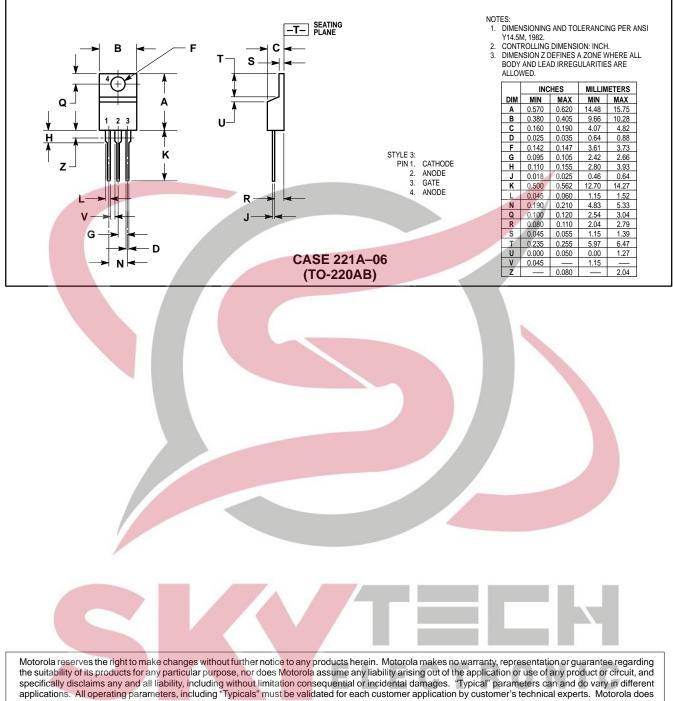
MCR16 SERIES



Motorola Thyristor Device Data

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PACKAGE DIMENSIONS



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